Modulators

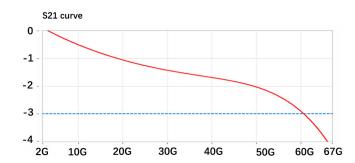
IQ Modulator

for Coherent Communication (1550)

■ Bandwidth up to 70 GHz

- Half-wave Voltage as low as 3.0 V
- Insertion loss as low as 6 dB
- **■** High Stability and Reliability







Modulators

■ Integrated low-RIN laser source

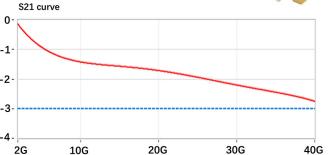
- Bandwidth up to 40 GHz
- Half-wave Voltage as low as 3.0 V
- Output Optical Power > 12 dBm
- Operating Temperature: -40 to 70 °C



Intensity Modulator

with Build-in LD

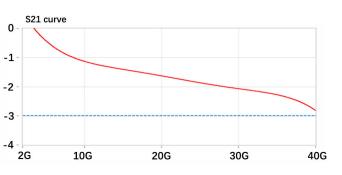
(1310/1550)



Phase Modulator (1310/1550)



- Bandwidth up to 40 GHz
- Insertion loss as low as 4.5 dB
- Half-wave Voltage as low as 3 V
- Maximum RF Input Power 33 dBm



Modulators

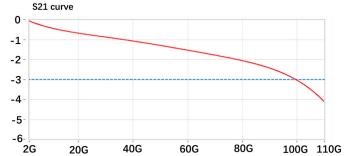
■ Compact Size (mm) = 45 * 10 * 7

- Bandwidth up to 110 GHz
- Insertion loss as low as 5 dB

High Bandwidth

- **Intensity Modulator**
- (1310/1550)



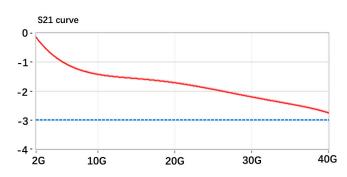


Intensity Modulator

(1310/1550)



- Bandwidth up to 40 GHz
- Half-wave Voltage as low as 2.5 V
- Insertion loss as low as 4.5 dB
- (Optional) Ultra-low voltage of 0.3/0.5 V



Lasers

Narrow Linewidth

■ Center wavelength:1551.4 nm

Offset Frequency (Hz)

Linear fitted

线性度: 99.93%

25

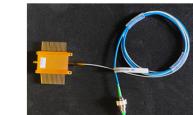
带宽: 8.2GHz

20

Time (µs)

- Output power:8 dBm
- Intrinsic linewidth: ≤ 200 Hz
- Chirp bandwidth: > 8.2 GHz
- Chirp linearity: > 0.9993

Tunable Laser



■ Built-in DFB Laser Automatic Bias Control ■ Tunable Bias Point / **Light Output Attenuation**

■ Output Optical Power > 10 dBm

■ Bandwidth up to 110 GHz, customizable

Transmitter



EO Transmitter

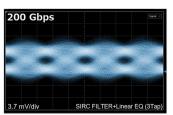
(1310/1550)

LD Output Power: +15dBm MZM Output Power: +6dBm

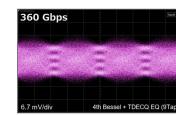
MZM: V_{pc} =0.8V, V_{pp} =2.4V (set value)

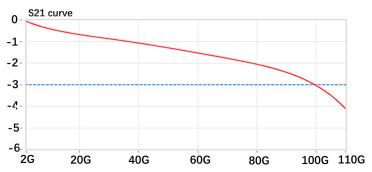
PD Photocurrent: 1mA PD Bandwidth: 90GHz Oscilloscope: Pattern Lock

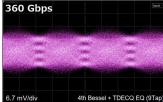
NRZ(OOK)



Pam4



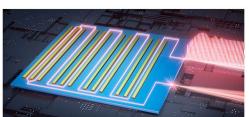




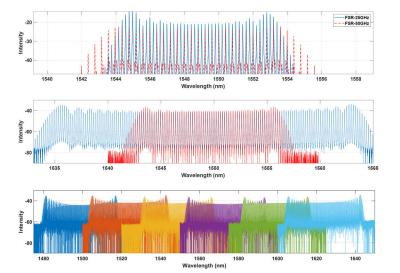
EO Combs

- Tunable comb spacing
- Scalable number of comb lines
- Tunable center wavelength





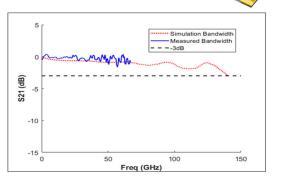
	ЕО	Vpi	IL	Number of comb lines	Notes
Comb-One-drags-one	30G	1.2V	≤9dB	>50	One AM cascaded with one PM
Comb-One-drags-three	25G	2.0V	≤10dB	>100	One AM cascaded with three PM
Dual-Comb	30G	2.0V	≤12dB	>80	[One AM cascaded with two PM] *2

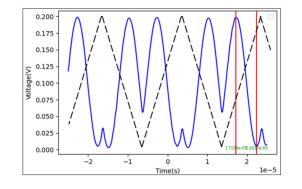


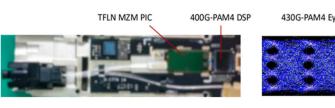
400G PAM4

PIC

- Bandwidth:>140 GHz (0.5 dB roll-off @70 GHz)
- 4-channel MZM
- Half-wave Voltage:<2.7 V</p>
- Support Differential Drive Mode
- Driver flip-chip



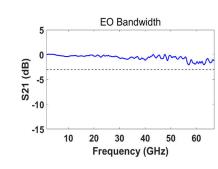




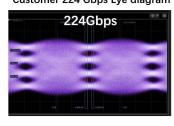
PIC

100G/200G IMDD

- Bandwidth:>70 GHz
- Insertion Loss:<11.5 dB (DR4)
- Half-wave Voltage:<3 V
- DC-ER:>40 dB
- MFD:>9 µm
- Chip size:>5.8*4*0.68 mm³
- Support Differential Drive Mode

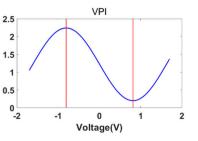


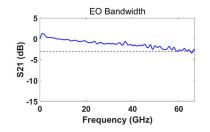
TDECQ < 0.5 dB Customer 224 Gbps Eye diagram 224Gbps



128GBaud PDMIQ

- Bandwidth:>60 GHz
- Insertion Loss:<6.5 dB
- Half-wave Voltage:<1.7 V @diff.
- DC-ER:>40 dB
- MFD:>9 µm
- Chip size:11.5*4.5*0.68 mm³





COMPANY INTRODUCTION

Liobate Technologies Limited (Liobate) was incorporated in July 2020 as a high-tech enterprise dedicated to developing lithium niobate modulator photonic integrated circuits (PICs) and related optical communications and interconnect sub-assemblies. Liobate is headquartered in Gulou District, Nanjing, in a facility that houses R&D, device pilot testing, and component packaging. Our wholly-owned subsidiary company, Guangzhou Liobate Semiconductor Technology Co., Ltd., is located in Guangzhou and is mainly developing lithium niobate on insulator (LNOI) modulators.

Liobate gathers specialists who worked in top-notch international institutions and enterprises in the field. Prof. Cai, the board chairman and the core technology leader, is the world-known expert in optoelectronics and was awarded the "China Top 10 Breakthroughs in Optics" in 2019,2020 and 2022. The technical team has made significant breakthroughs in LNOI modulator chip technology and has built a complete process platform and mass production line covering chip design, fabrication, and device packaging. The company owns top-of-the-field level invention patents and leading technologies.

Liobate focuses on the design, fabrication, and sales of PICs and optical modules based on lithium niobate modulators. Liobate specializes in the telecommunication and data interconnect market, creating faster and more energy-efficient physical transmission channels. Liobate is committed to high standards of social and environmental responsibility

Liobate has key expertise and is well equipped for making significant technical progress in advanced optical communications and interconnects technologies. Liobate adopts a strict product quality assurance system as well as a flexible and efficient management structure.







CONTACT US: sales@liobate.com



